



XGF06
6KV, 150 mA
Fast Recovery
High Voltage Diode



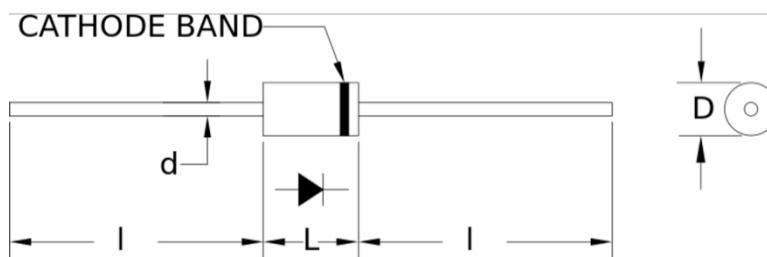
Features

- High voltage, higher current diode in small form factor
- Molded plastic body, ANSI/UL94 V-0 rated material
- Uses new Dean Technology, XOE Technology
- RoHS compliant to Directive 2011/65/EC, Article 4(1), Annex II; Annex III, 7(a) and EU RoHS Directive (EU) 2015/863 of March 2015, Amending Annex II.

Device Electrical Characteristics*	Conditions	Symbol	Value
Maximum Repetitive Peak Reverse Voltage	-	V_{RRM}	6,000 Volts
Average Forward Current maximum	$T_{AIR} = 55^{\circ}\text{C}$	I_{FAVM}	150 mA
Average Forward Current maximum	$T_{OIL} = 55^{\circ}\text{C}$	I_{FAVM}	300 mA
Maximum Forward Voltage Drop	$I_F = 300 \text{ mA}, t_{PW} = 100\mu\text{sec}$	V_F	10.2 Volts
Typical Thermal Resistance (junction to ambient)	In air	$R_{\Theta JA}$	73 °C/W
Maximum Surge Current rating	8.3msec, half sine	I_{FSM}	15 Amps
Maximum Reverse Current	at rated V_{RRM}	I_R	0.2 μA
Maximum Reverse Recovery Time	$I_F=75\text{mA}; I_R=-150\text{mA}; I_{RR}=-37\text{mA}$	TRR	80 ns
Maximum Reverse Energy Withstand	-	E_{RSW}	200 mJ
Typical Junction Capacitance	$f = 1\text{Mhz}, V_r = 0\text{VDC}$	C_J	5.4 pF
Maximum Junction Temperature	-	T_J	125°C
Storage Temperature Range	-	T_{STG}	-55°C to 175°C

(*Note: 25°C ambient temperature unless stated otherwise.)

Mechanical Data	Min.		Max.	
	in.	mm	in.	mm
Body length	L	-	-	0.32
Body diameter	D	-	-	0.12
Lead length	l	1.0	25.4	-
Lead diameter	d	-	-	0.025



Forward Current vs. Typical Forward Voltage Drop
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